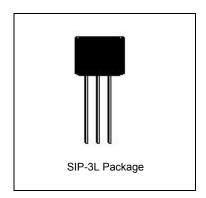
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H177

Single Output Hall Effect Latch IC

General Description

H177 is an integrated Hall effect latched sensor with output pull-high resistor driver designed for electronic commutation of brushless DC motor applications and contactless switches.



The device includes an on-chip Hall voltage generator for magnetic sensing, a comparator that amplifies the Hall voltage, and a Schmitt trigger to provide switching hysteresis for noise rejection, and output driver with pull-high resistor. An internal bandgap regulator is used to provide temperature compensated supply voltage for internal circuits and allows a wide operating supply range. If a magnetic flux density larger than threshold Bop, DO is turned on (Low). The output state is held until a magnetic flux density reversal falls below Brp causing DO to be turned off (High).

H177 is rated for operation over temperature range from -20℃ to 85℃ and voltage range from 3.5V to 28V. The devices are available in low cost die forms or rugged 3 pin SIP packages.

Features

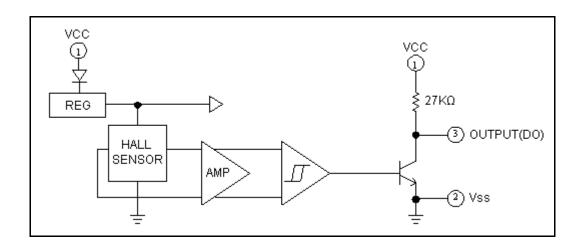
- Wide range of supply voltage: 3.5V to 28V.
- Internal bandgap regulator allows temperature compensated operations and a wide operating voltage range.
- High sensitivity with a small magnet.
- TTL and MOS ICs directly drivable by output.
- Build in protection diode for chip reverse power connecting.
- Package: SIP-3L.

Applications

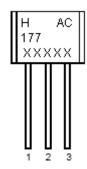
- Brushless DC Motor
- Brushless DC Fan
- Position Sensors
- Rotation Sensors
- Revolution Counting
- Speed Measurement
- Keyboard Switches
- Micro-switches

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Functional Block Diagram



Pin Assignment



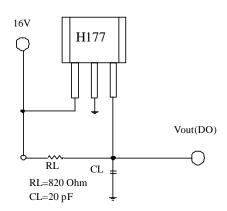
Name	P/I/O	Pin No	Description
VCC	Р	1	Positive Power Supply
Vss	Р	2	Gnd
DO	0	3	Output Pin

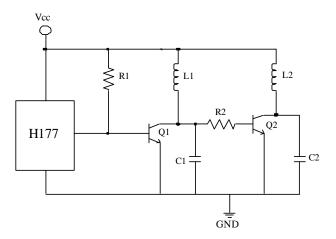
Absolute Maximum Ratings (Ta=25°C)

Characteristics	Symbol	Values	Unit
Supply Voltage	V _{CC}	28	V
Reverse VCC Polarity Voltage	V _{RCC}	-28	V
Magnetic Flux Density	В	Unlimited	
Output OFF Voltage	V _{ce}	35	V
Output ON Current (continuous)	Ic	25	mA
Operating Temperature Range	T _A	-20 to +85	$^{\circ}$
Storage Temperature Range	T _S	-65 to +150	°C
Package Power Dissipation	P _D	250	mW
Maximum Junction Temperature	T _J	150	$^{\circ}$

Spec. No.: IC200914 Issued Date : 2009.08.12 Revised Date :2010,01,18 Page No. : 3/6

Test Circuit & Application Circuit





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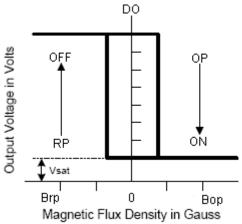
Electrical Characteristics (Ta=+25°C)

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Supply Voltage	V _{CC}		3.5	-	28	V	
Low output voltage		V _{CC} =16V,Io=12mA,B=130 G	-	-	0.4	V	
	V _{OL}	V _{CC} =3.6V,lo=12mA,B=130 G	-	-	0.4		
High output voltage		V _{CC} =16V,Io=-30μA,B=-130 G	14.6	-	-	V	
	V _{OH}	V _{CC} =3.6V,Io=-30μA,B=-130 G	2.2	-	-		
Output Leakage Current	Icex	Vce=16V, V _{CC} =16V	-	0.1	10	uA	
Output Short-circuit Current	-los	V _{CC} =16V,Vo=0V,B=-130 G	0.4	-	0.9	mA	
Supply Current	Icc	V _{CC} =24V, Output Open	-	5	10	mA	
Output Rise Time	tr	V _{CC} =16V, RL=820Ω, CL=20Pf	-	0.3	1.5	us	
Output Falling Time	tf	V _{CC} =16V, RL=820Ω, CL=20Pf	-	0.3	1.5	us	

Magnetic Characteristics

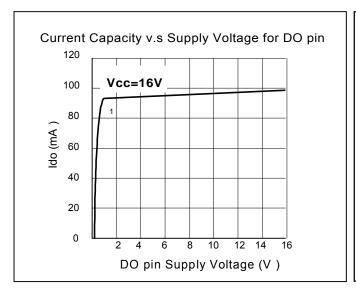
Characteristic		Symbol	Ta=+25℃		Ta=0°C to +70°C		Unit	grade
		Symbol	Min.	Max.	Min.	Max.		grado
Ope	Operate Point	Вор	0	70	0	70	G	
H177A	Release Point	Brp	-70	0	-70	0	G	Α
	Hysteresis	Bhys	40	110	20	140	G	
	Operate Point	Вор	-	100	-	100	G	
H177B	Release Point	Brp	-100	-	-100	-	G	В
	Hysteresis	Bhys	50	150	30	200	G	
	Operate Point	Вор	-	130	-	130	G	
H177C	Release Point	Brp	-130	-	-130	-	G	С
	Hysteresis	Bhys	60	160	40	220	G	

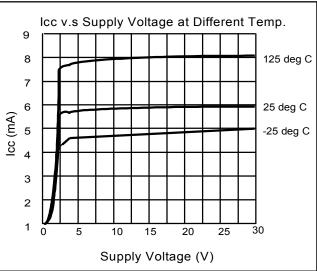
Hysteresis Characteristics Curve

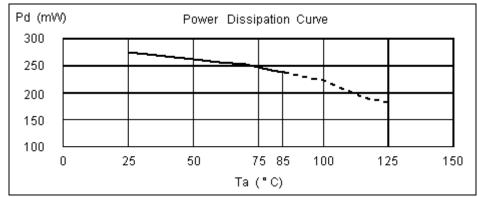


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Electrical Characteristics Curve

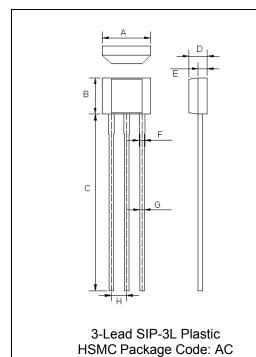


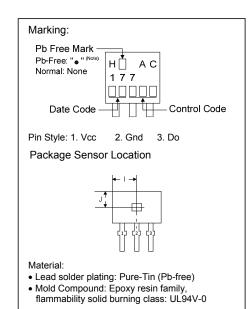




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SIP-3L Dimension





DIM	Min.	Max.		
Α	3.962	4.216		
В	2.870	3.124		
C	13.60	15.60		
D	1.245	1.753		
Е	0.750REF			
F	0.406	0.508		
G	0.330	0.432		
Н	1.27REF			
I	1.87	2.13		
J	1.37	1.63		

*: Typical, Unit: mm

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